TP5335

P-Channel Enhancement-Mode Vertical DMOS FET

Features

- High Input Impedance and High Gain
- Low-Power Drive Requirement
- Ease of Paralleling
- Low C_{ISS} and Fast Switching Speeds
- Excellent Thermal Stability
- Integral Source-Drain Diode
- Free from Secondary Breakdown

Applications

- Logic-Level Interfaces (Ideal for TTL and CMOS)
- Solid-State Relays
- Analog Switches
- Power Management
- Telecommunication Switches

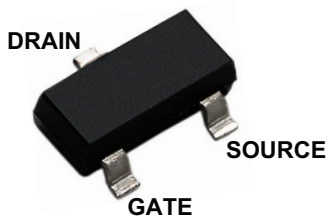
General Description

The TP5335 is a low-threshold, Enhancement-mode (normally-off) transistor that utilizes an advanced vertical DMOS structure and a well-proven silicon-gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors and the high input impedance and positive temperature coefficient inherent in MOS devices. The characteristic of all MOS structures is that this device is free from thermal runaway and thermally induced secondary breakdown.

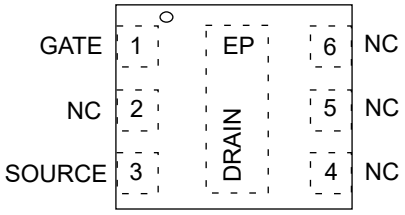
Microchip's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

Package Type

3-lead SOT-23
(Top view)



6-lead DFN
(Top view)



See Table 2-1 for pin information.

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1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings(†)

Drain-to-Source Voltage ..... BV_{DSS}
Drain-to-Gate Voltage ..... BV_{DGS}
Gate-to-Source Voltage ..... ±20V
Junction Temperature, T_J ..... -55°C to +150°C
Storage Temperature, T_S ..... -55°C to +150°C
ESD Protection (HBM) TP5335MF-G
- Drain-to-Source ..... ±6 kV
- Gate-to-Drain ..... +500V
- Gate-to-Source ..... <±250V

ESD Protection (CDM) TP5335MF-G ..... 1 kV

† **Notice:** Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS – COMMERCIAL

Electrical Specifications: $T_A = T_J = 25°C$ unless otherwise specified. All DC parameters are 100% tested at 25°C unless otherwise stated. (Pulse test: 300 µs pulse, 2% duty cycle.)

Parameter	Sym.	Min.	Typ.	Max.	Unit	Conditions
Drain-to-Source Breakdown Voltage	BV_{DSS}	-350	—	—	V	V_{GS} = 0V, I_D = -100 µA
Gate Threshold Voltage	$V_{GS(th)}$	-1	—	-2.4	V	$V_{DS} = V_{GS}$, I_D = -1 mA
Change in $V_{GS(th)}$ with Temperature	$\Delta V_{GS(th)}$	—	—	4.5	mV/°C	$V_{DS} = V_{GS}$, I_D = -1 mA (**Note 1**)
Gate Body Leakage	I_{GSS}	—	—	-100	nA	V_{GS} = ±20V, V_{DS} = 0V
Zero-Gate Voltage Drain Current	I_{DSS}	—	—	-10	µA	V_{DS} = Maximum rating, V_{GS} = 0V
		—	—	-1	mA	V_{DS} = Maximum rating, V_{GS} = 0V, T_A = 125°C (**Note 1**)
On-State Drain Current	$I_{D(ON)}$	-200	—	—	mA	V_{GS} = -4.5V, V_{DS} = -25V
		-400	—	—	mA	V_{GS} = -10V, V_{DS} = -25V
Static Drain-to-Source On-State Resistance	$R_{DS(ON)}$	—	—	75	Ω	V_{GS} = -4.5V, I_D = -150 mA
		—	—	30	Ω	V_{GS} = -10V, I_D = -200 mA
Change in $R_{DS(ON)}$ with Temperature	$\Delta_{RDS(ON)}$	—	—	1.7	%/°C	V_{GS} = -10V, I_D = -200 mA (**Note 1**)

Note 1: Specification is obtained by characterization and is not 100% tested.

DC ELECTRICAL CHARACTERISTICS – AUTOMOTIVE

Electrical Specifications: Boldface specification limits apply over the full operating temperature range of $T_A = T_J$ = -55°C, 25°C, and 150°C unless otherwise specified. Non-boldfaced specification limits apply only to $T_A = T_J$ = 25°C unless otherwise specified. All DC parameters are 100% tested at all three temperatures unless otherwise specified. (Pulse test: 300 µs pulse, 2% duty cycle.)

Parameter	Sym.	Min.	Typ.	Max.	Unit	Conditions
Drain-to-Source Breakdown Voltage	BV_{DSS}	**-350**	—	—	V	V_{GS} = 0V, I_D = -100 µA

Note 1: Specification is obtained by characterization and is not 100% tested.

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DC ELECTRICAL CHARACTERISTICS – AUTOMOTIVE (CONTINUED)

Electrical Specifications: Boldface specification limits apply over the full operating temperature range of $T_A = T_J$ = -55°C, 25°C, and 150°C unless otherwise specified. Non-boldfaced specification limits apply only to $T_A = T_J$ = 25°C unless otherwise specified. All DC parameters are 100% tested at all three temperatures unless otherwise specified. (Pulse test: 300 µs pulse, 2% duty cycle.)

Parameter	Sym.	Min.	Typ.	Max.	Unit	Conditions
Gate Threshold Voltage	$V_{GS(th)}$	-1	—	**-2.4**	V	$V_{DS} = V_{GS}$, I_D = -1 mA
Change in $V_{GS(th)}$ with Temperature	$\Delta V_{GS(th)}$	—	3.3	—	mV/°C	$V_{DS} = V_{GS}$, I_D = -1 mA (**Note 1**)
Gate Body Leakage	I_{GSS}	—	—	-100	nA	V_{GS} = ±20V, V_{DS} = 0V
		—	—	**-220**	nA	V_{GS} = ±20V, V_{DS} = 0V
Zero-Gate Voltage Drain Current	I_{DSS}	—	—	–10	µA	V_{DS} = Maximum rating, V_{GS} = 0V
		—	—	**-1**	mA	V_{DS} = Maximum rating, V_{GS} = 0V
On-State Drain Current	$I_{D(ON)}$	**-200**	—	—	mA	V_{GS} = -4.5V, V_{DS} = -25V
		-400	—	—	mA	V_{GS} = -10V, V_{DS} = -25V
		-375	—	—	mA	V_{GS} = -10V, V_{DS} = -25V
Static Drain-to-Source On-State Resistance	$R_{DS(ON)}$	—	—	**75**	Ω	V_{GS} = -4.5V, I_D = -150 mA
		—	—	30	Ω	V_{GS} = -10V, I_D = -200 mA
		—	—	**70**	Ω	V_{GS} = -10V, I_D = -200 mA
Change in $R_{DS(ON)}$ with Temperature	$\Delta_{RDS(ON)}$	—	1	—	%/°C	V_{GS} = -10V, I_D = -200 mA (**Note 1**)

Note 1: Specification is obtained by characterization and is not 100% tested.

AC ELECTRICAL CHARACTERISTICS – COMMERCIAL

Electrical Specifications: $T_A = T_J$ = 25°C unless otherwise specified. Specification is obtained by characterization and is not 100% tested.

Parameter	Sym.	Min.	Typ.	Max.	Unit	Conditions
Forward Transconductance	G_{FS}	125	—	—	mmho	V_{DS} = -25V, I_D = -200 mA
Input Capacitance	C_{ISS}	—	—	110	pF	V_{GS} = 0V, V_{DS} = -25V, f = 1 MHz
Common Source Output Capacitance	C_{OSS}	—	—	60	pF	
Reverse Transfer Capacitance	C_{RSS}	—	—	22	pF	
Turn-On Delay Time	$t_{d(ON)}$	—	—	20	ns	V_{DD} = -25V, I_D = -150 mA, R_{GEN} = 25Ω
Rise Time	t_r	—	—	15	ns	
Turn-Off Delay Time	$t_{d(OFF)}$	—	—	25	ns	
Fall Time	t_f	—	—	25	ns	
DIODE PARAMETER						
Diode Forward Voltage Drop	V_{SD}	—	—	-1.8	V	V_{GS} = 0V, I_{SD} = -200 mA (**Note 1**)
Reverse Recovery Time	t_{rr}	—	800	—	ns	V_{GS} = 0V, I_{SD} = -200 mA

Note 1: All DC parameters are 100% tested at 25°C unless otherwise stated.(Pulse test: 300 µs pulse, 2% duty cycle.)

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AC ELECTRICAL CHARACTERISTICS – AUTOMOTIVE

Electrical Specifications: $T_A = T_J = 25°C$ unless otherwise specified. Specification is obtained by characterization and is not 100% tested.

Parameter	Sym.	Min.	Typ.	Max.	Unit	Conditions
Forward Transconductance	G_{FS}	—	285	—	mmho	V_{DS} = -25V, I_D = -200 mA
Input Capacitance	C_{ISS}	—	80	—	pF	V_{GS} = 0V, V_{DS} = -25V, f = 1 MHz
Common Source Output Capacitance	C_{OSS}	—	12	—	pF	
Reverse Transfer Capacitance	C_{RSS}	—	2	—	pF	
Turn-On Delay Time	$t_{d(ON)}$	—	7.6	—	ns	V_{DD} = -25V, I_D = -150 mA, R_{GEN} = 25Ω
Rise Time	t_r	—	3	—	ns	
Turn-Off Delay Time	$t_{d(OFF)}$	—	19	—	ns	
Fall Time	t_f	—	10	—	ns	
DIODE PARAMETER						
Diode Forward Voltage Drop	V_{SD}	—	—	-1.8	V	V_{GS} = 0V, I_{SD} = -200 mA (**Note 1**)
Reverse Recovery Time	t_{rr}	—	450	—	ns	V_{GS} = 0V, I_{SD} = -200 mA

Note 1: 100% Production Tested at $T_A = T_J$ = (-55°C, 25°C, and 150°C).

TEMPERATURE SPECIFICATIONS

Parameter	Sym.	Min.	Typ.	Max.	Unit	Conditions
TEMPERATURE RANGE						
Operating Junction Temperature	T_J	-55	—	+150	°C	
Storage Temperature	T_S	-55	—	+150	°C	
PACKAGE THERMAL RESISTANCE						
3-lead SOT-23	θ_{JA}	—	203	—	°C/W	
6-lead DFN	θ_{JA}	—	102	—	°C/W	

THERMAL CHARACTERISTICS

Package	I_D (Note 1) (Continuous) (mA)	I_D (Pulsed) (mA)	Power Dissipation at T_A = 25°C (W)	I_{DR} (Note 1) (mA)	I_{DRM} (mA)
3-lead SOT-23	-85	-400	0.36	-85	-400

Note 1: I_D (continuous) is limited by maximum T_J.

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2.0 PIN DESCRIPTION

Table 2-1 shows the description of pins in TP5335 SOT-23. Refer to **Package Type** for the location of pins.

TABLE 2-1: PIN FUNCTION TABLE

Pin Number 3-Lead SOT-23	Pin Number 6-Lead DFN	Pin Name	Description
1	1	Gate	Gate
2	3	Source	Source
—	2	NC	Not Connected
3	4, 5, 6	NC	Not Connected. It is recommended to connect to drain.
—	EP	Drain	Drain

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3.0 FUNCTIONAL DESCRIPTION

Figure 3-1 illustrates the switching waveforms and test circuit for TP5335.

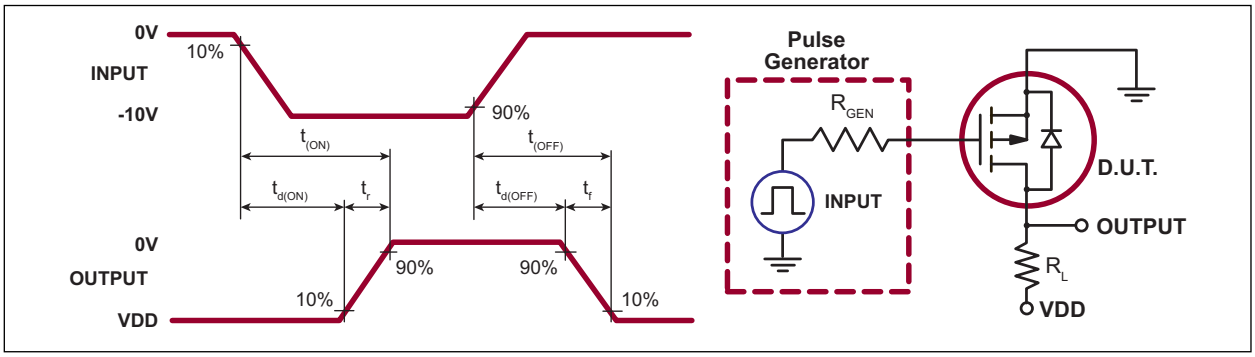


FIGURE 3-1: *Switching Waveforms and Test Circuit.*

TABLE 3-1: PRODUCT SUMMARY

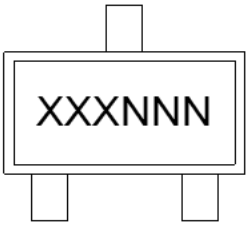
BV_{DSS}/BV_{DGS} (V)	$R_{DS(ON)}$ (Maximum) (Ω)	$V_{GS(th)}$ (Maximum) (V)
-350	30	-2.4

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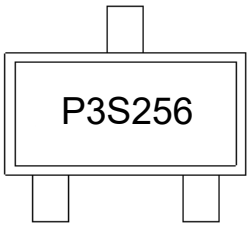
4.0 PACKAGING INFORMATION

4.1 Package Marking Information

3-Lead SOT-23
(2.90 mm x 1.30 mm)



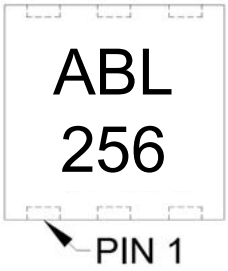
Example



6-Lead DFN
(2 mm x 2 mm)



Example



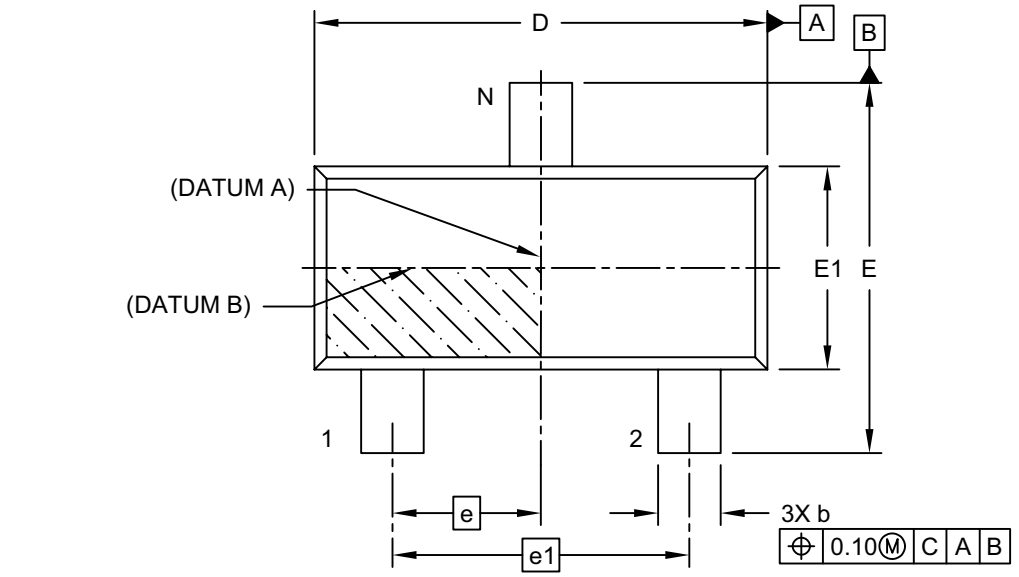
Legend:	XX...X	Product Code or Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week ‘01’)
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator ((e3)) can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or not include the corporate logo.

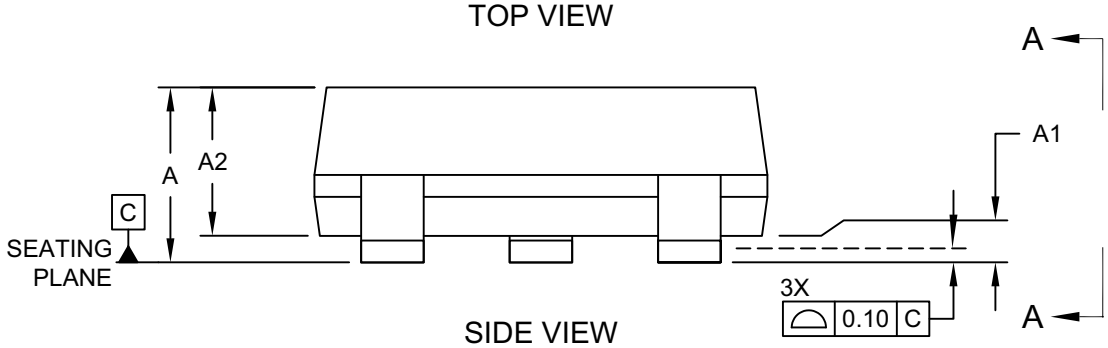
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3-Lead Small Outline Transistor (C6X) - [SOT-23]
Supertex Legacy Package (K1/T)

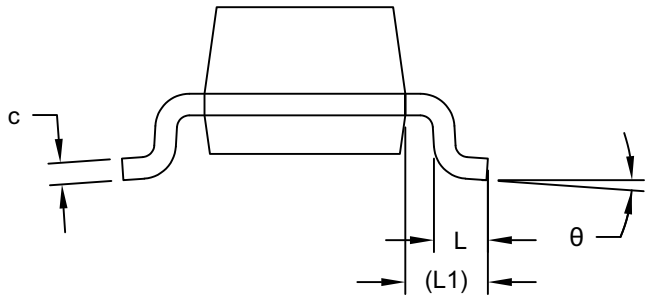
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



TOP VIEW



SIDE VIEW



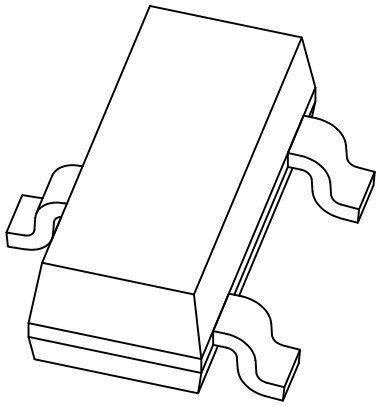
VIEW A–A

Microchip Technology Drawing C04-17458 Rev A Sheet 1 of 2

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3-Lead Small Outline Transistor (C6X) - [SOT-23]
Supertex Legacy Package (K1/T)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Terminals	N		3	
Pitch	e		0.95 BSC	
Overall Pitch	e1		1.90 BSC	
Overall Height	A	0.89	–	1.12
Standoff	A1	0.01	–	0.10
Molded Package Thickness	A2	0.88	0.95	1.02
Overall Length	D	2.80	2.90	3.04
Overall Width	E	2.10	–	2.64
Molded Package Width	E1	1.20	1.30	1.40
Terminal Width	b	0.30	–	0.50
Terminal Thickness	c	0.08	–	0.20
Terminal Length	L	0.20	0.50	0.60
Footprint	L1		0.54 REF	
Foot Angle	θ	0°	-	8°

Notes:

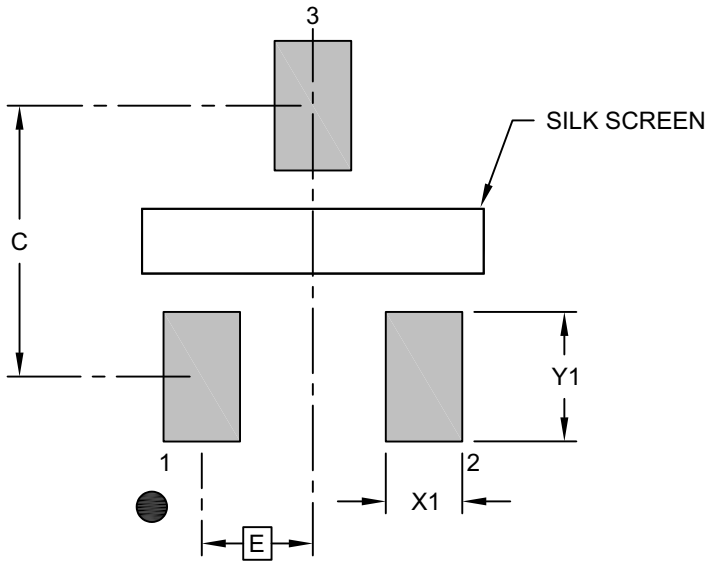
1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
   REF: Reference Dimension, usually without tolerance, for information purposes only.

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3-Lead Small Outline Transistor (C6X) - [SOT-23]
Supertex Legacy Package (K1/T)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		0.95 BSC	
Contact Pad Spacing	C		2.30	
Contact Pad Width (X3)	X1			0.65
Contact Pad Length (X3)	Y1			1.10

Notes:

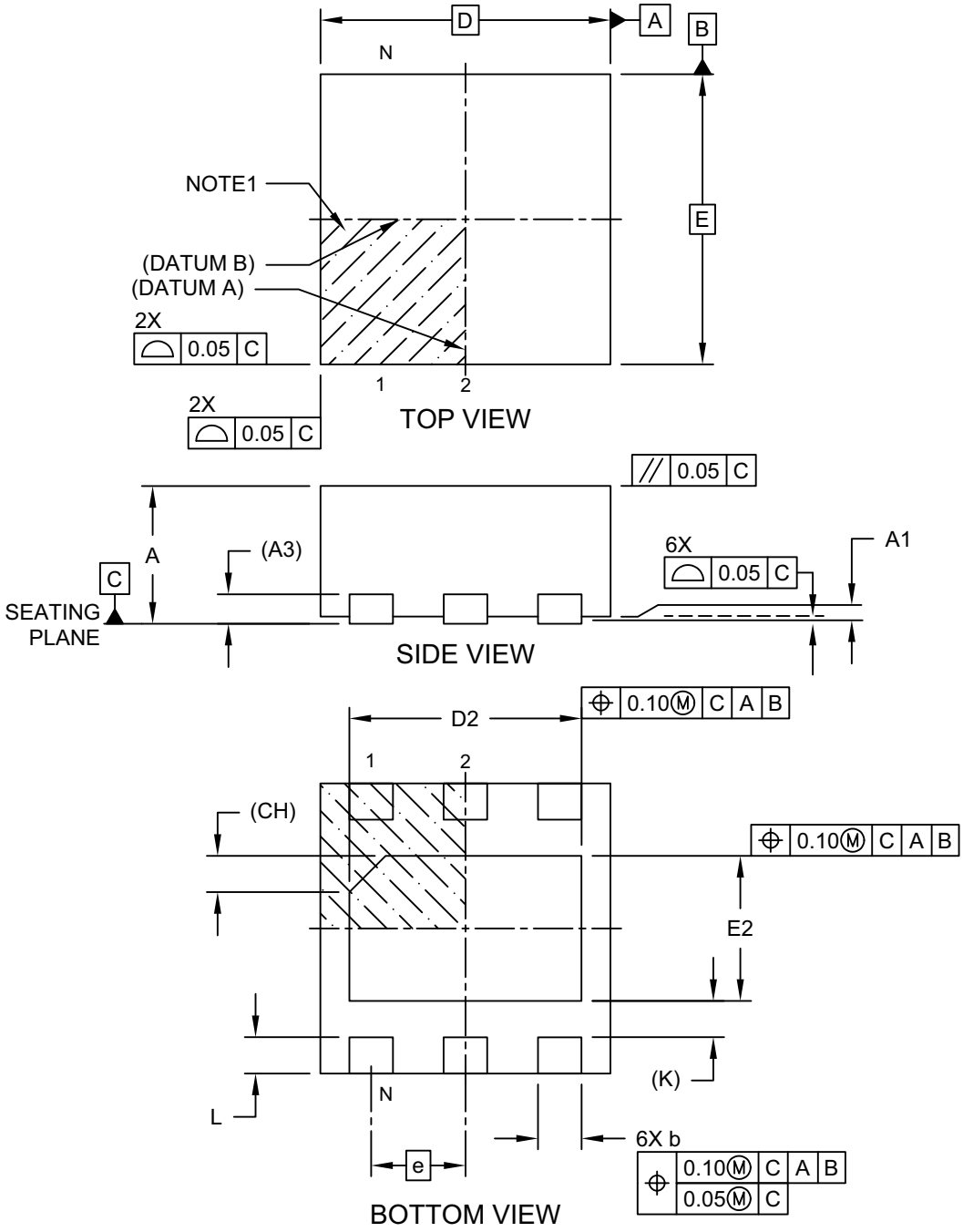
1. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-19458 Rev A

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6-Lead Plastic Dual Flat, No Lead Package (7AX) - 2x2x0.9 mm Body [DFN]

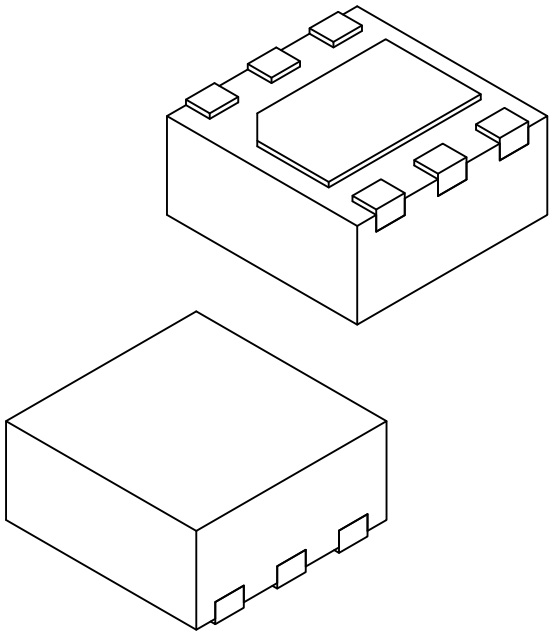
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-120-7AX Rev D Sheet 1 of 2

6-Lead Plastic Dual Flat, No Lead Package (7AX) - 2x2x0.9 mm Body [DFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Terminals	N		6	
Pitch	e		0.65 BSC	
Overall Height	A	0.80	0.87	0.95
Standoff	A1	0.00	0.02	0.05
Terminal Thickness	A3		0.203 REF	
Overall Length	D		2.00 BSC	
Exposed Pad Length	D2	1.50	1.60	1.70
Overall Width	E		2.00 BSC	
Exposed Pad Width	E2	0.90	1.00	1.10
Chamfer	CH		0.25 REF	
Terminal Width	b	0.25	0.30	0.35
Terminal Length	L	0.20	0.25	0.30
Terminal-to-Exposed-Pad	K		0.25 REF	

Notes:

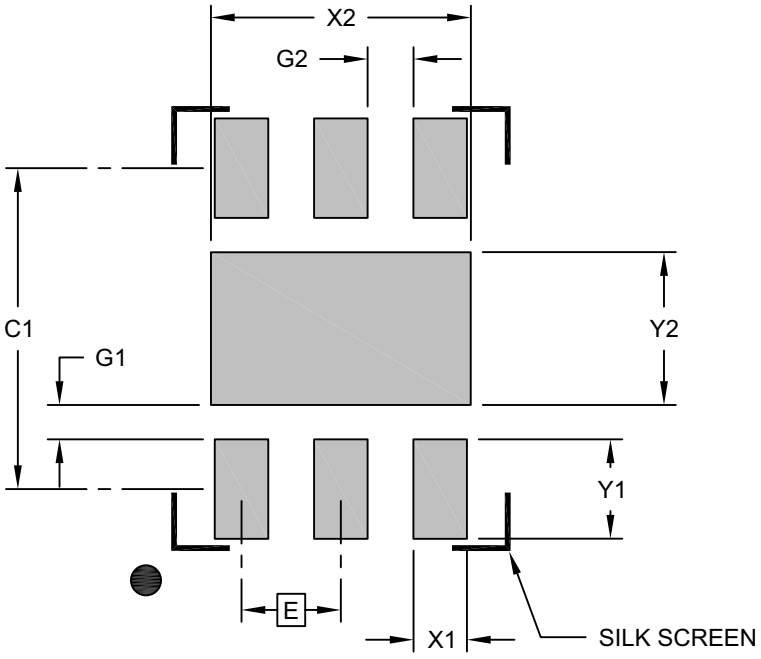
1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Package is saw singulated
3. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
   REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-120-7AX Rev D Sheet 2 of 2

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6-Lead Plastic Dual Flat, No Lead Package (7AX) - 2x2x0.9 mm Body [DFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		0.65 BSC	
Center Pad Width	X2			1.70
Center Pad Length	Y2			1.00
Contact Pad Spacing	C1		1.70	
Contact Pad Width (X6)	X1			0.35
Contact Pad Length (X6)	Y1			0.65
Contact Pad to Center Pad (X6)	G1	0.20		
Contact Pad to Contact Pad (X4)	G2	0.25		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

   BSC: Basic Dimension. Theoretically exact value shown without tolerances.

2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-2120-7AX Rev D

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NOTES:

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APPENDIX A: REVISION HISTORY

Revision E (April 2023)

- Added package 6-lead DFN and related information throughout the document.
- Made minor text changes throughout the document.

Revision D (March 2022)

- Updated tables DC Electrical Characteristics – Automotive and AC Electrical Characteristics – Automotive.
- Updated Section 4.1 “Package Marking Information”.
- Updated Product Identification System format.
- Updated legal and contact information.

Revision C (June 2020)

- Added automotive specifications to the Electrical Characteristics section.
- Added automotive specifications to the Product Identification System section.
- Made minor text changes throughout the document.

Revision B (February 2020)

- Revised the order of pins in the Pin Function Table.
- Revised the Electrical Specifications and included notes in the DC Electrical Characteristics and AC Electrical Characteristics tables.
- Made minor text changes throughout the document.

Revision A (December 2018)

- Converted Supertex Doc# DSFP-TP5335 to Microchip DS20005704A.
- Made minor text changes throughout the document.

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NOTES:

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PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

PART NO.	XX	-X	-XXX
Device	Package	Environmental	Qualification

Device:	TP5335:	P-Channel Enhancement-Mode Vertical DMOS FET
Package:	K1	= 3-lead SOT-23
	MF	= 6-lead DFN
Environmental:	G	= Lead (Pb)-free/RoHS-compliant Package
Media Type:	(Blank)	= 3000/Reel for a K1 Package = 3000/Reel for a MF Package
Qualification:	(Blank)	= Standard Part
	VAO	= Automotive AEC-Q100 Qualified

Examples:

a) TP5335K1-G: P-Channel Enhancement-Mode Vertical DMOS FET, 3-lead SOT-23, 3000/Reel

b) TP5335K1-G-VAO: P-Channel Enhancement-Mode Vertical DMOS FET, 3-lead SOT-23, 3000/Reel, Automotive Qualified

c) TP5335MF-G-VAO: P-Channel Enhancement-Mode Vertical DMOS FET, 6-lead DFN, 3000/Reel, Automotive Qualified

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NOTES:

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- Microchip products meet the specifications contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is secure when used in the intended manner, within operating specifications, and under normal conditions.
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